

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,220,489 B1
APPLICATION NO. : 10/826645
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INVENTOR(S) : Chang Wei et al.

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It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 5, line 43 "SiO_xN_y layer 3201," should read -- SiO_xN_y layer 320₁, --.

Signed and Sealed this

Nineteenth Day of August, 2008



JON W. DUDAS
Director of the United States Patent and Trademark Office